Auto- versus cross-correlation noise

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Charge conservation tightly links the time-averaged fluctuations in electrical currents at the leads of the multi-terminal conductor. However, the ability to dynamically accumulate charge disentangles fluctuations with non-zero frequency in different leads. When current is carried by non-overlapping wave-packets, then the product of current fluctuations in different leads, the cross-correlation noise, is determined solely by the duration of the wave packet. In contrast, the square of the current fluctuations in one lead, the auto-correlation noise, is additionally determined by the coherence of the wave-packet, which is associated with the spread of the wave packet in energy. The two contributions can be addressed separately in the weak back-scattering regime, when the auto-correlation noise depends only on the coherence. Analysis of these contributions allows us to make predictions related to the temperature dependence of noise, and also that no single particles with a real wave function, such as Majorana fermions, can be created in the Fermi sea in a clean manner, that is, without accompanying electron-hole pairs.

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I. INTRODUCTION

Recently the quantum tomography of a single electron wave function was demonstrated experimentally.\textsuperscript{1,2} In both experiments, a periodic stream of single-electron wave packets was mixed with a low amplitude electrical probe signal at the electron wave splitter, a quantum point contact and the resulting electrical noise averaged over long time was measured. However, if the fluctuations of an electrical current within one output lead were measured in one experiment, the correlations of currents flowing within both output leads were measured in another. In a sense, these works are the culmination of a number of recent works where the cross-correlation noise was measured to count electrons emitted per period\textsuperscript{3,4}, to demonstrate a tunable fermionic anti-bunching\textsuperscript{4–7}, and the auto-correlation noise at high\textsuperscript{8,9} and low\textsuperscript{10,11} frequencies was measured to identify a single-electron emission regime. These experimental advances stimulate us to take a closer look at how exactly the quantum properties of a wave packet manifest themselves in the measured electrical noise\textsuperscript{12–14}.

Note also that tomography of the density profile of solitary electrons was successfully realized in Ref. 15 using the measurements of the electrical current rather than noise.

Here, in contrast to previous works\textsuperscript{16–32}, – for a review, see Ref. 33– I will focus on comparing auto- and cross-correlation noise. I will show that, in the case of a periodic train of non-overlapping single-electron wave packets scattered off the wave splitter with reflection probability $R$, there are two contributions to noise. They can be addressed separately by measuring both tapes of noise in the weak back-scattering regime, $R \ll 1$. In particular, for a single-electron wave packet $\Psi (t) = e^{-i\mathcal{H}t} \psi (t)$ injected during one period into a chiral wave guide and reflected into a detector at a wave splitter, see Fig. 1,

\begin{figure}[h]
\centering
\includegraphics[width=0.8\textwidth]{fig1}
\caption{Shot noise of a single-electron wave packet consists of two parts. One is determined by the density profile of the wave packet, shown as a filled hump, and the other is determined by the coherence of the wave packet, shown as a double hump. While the former contributes to both auto-correlation noise, $P_{\text{auto}}$, and cross-correlation noise, $P_{\text{cross}}$, the latter contributes to $P_{\text{auto}}$ only. The solid arrow indicates the incoming wave packet, shown as an empty hump. The filled circle represents the wave spitter with reflection probability $R$ and transmission probability $T = 1 - R$. The two dashed arrows point to the two outgoing leads.}
\end{figure}

the auto-correlation, $P_{\text{auto}}$, and cross-correlation, $P_{\text{cross}}$, noise power at frequency $\omega$ and at zero temperature are calculated as follows,

\begin{align}
P_{\text{auto}}(\omega) &= R \epsilon^2 \frac{\epsilon^2}{\hbar} \int_{-\infty}^{\infty} d\tau e^{i\omega \tau} \text{Im} C(\tau) \frac{\pi \tau}{\pi \tau}, \\

P_{\text{cross}}(\omega) &= -R \epsilon^2 |N(\omega)|^2,
\end{align}

where the superscript $ex$ indicates the excess over the equilibrium value, $e$ is an electron charge, $T_0$ is a period, $C(t)$ is the integrated over time coherence of the wave function envelope, \(34,35\)

\[
C(t) = \int_{-\infty}^{\infty} dt \psi^*(t + \tau) \psi(t),
\]

and $N(\omega)$ is the Fourier transform of the wave packet density,

\[
N(\omega) = \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} |\psi(\tau)|^2.
\]

Thus, we see that in the weak backscattering regime, the auto-correlation noise and the cross-correlation noise are determined by essentially different quantities. One can say that they provides somehow complementary information. The cross-correlation noise is sensitive merely to the shape of a wave packet, that is, to its duration in time. While the auto-correlation noise is rather sensitive to how different parts of the wave packet correlate with each other. Such correlations are related to the spread of the wave packet in energy, which is supported by the reasoning of Ref. 9 that only those particles whose energy exceeds the Fermi energy by more than $\hbar\omega$ contribute to the auto-correlation noise at the frequency $\omega$. The following examples provide additional evidence of the duality of the information provided by both types of noise.

A Lorentzian voltage pulse, one per period, $eV(t) = 2\hbar\omega/\left(t^2 + \Gamma_0^2\right)^{-1}$, applied to the Fermi sea with energy $\mu$ and at zero temperature creates a single-electron wave packet \(36,37\), named a leviton \(4\), with the following wave function,

\[
\psi(t) = e^{-\frac{i}{\hbar}\mu t} \psi(t),
\]

where the envelope function is \(38\)

\[
\psi(t) = \frac{1}{\sqrt{\pi \Gamma_0}} \frac{\Gamma_0}{t - i\Gamma_0}.
\]

I assume $\Gamma_\tau \ll T_0$ to avoid overlap between the successive wave packets. Using the above equation in Eq. (1), I calculate,

\[
\mathcal{P}^{ex}_{auto}(\omega) = -\mathcal{P}^{c}_{cross}(\omega) = \frac{e^2}{T_0} e^{-|\omega|^2 \Gamma_\tau},
\]

The fact that the auto- and cross-correlation noise show the same frequency dependence is due to the fact that there is only one time parameter in the problem, $\Gamma_\tau$, which defines both the characteristic energy and its mean fluctuations, $\hbar/(2\Gamma_\tau)$, \(38\) and the characteristic width in time, $2\Gamma_\tau$.

In the next example the shape and the energy distribution are not related so tight and $\mathcal{P}^{ex}_{auto}(\omega)$ and $-\mathcal{P}^{c}_{cross}(\omega)$ become different.

Let us consider a quantum level of half-width $\Gamma$ filled with one electron and tunnel-coupled to a one dimensional Fermi sea at zero temperature. The energy of a level raises at a constant rapidity $c$, and crosses the Fermi level at $t = 0$ when an electron is injected into the Fermi sea. Such regime of injection can be realized using the quantum capacitor. \(39\) \(41\) The wave function of the injected electron was calculated in Ref. 42, $\psi(t) = e^{-\frac{i}{\hbar}\mu t} \psi(0)$, with

\[
\psi(0) = \frac{1}{\sqrt{\pi \Gamma_0}} \int_0^{\infty} dx e^{-|x|^2 \frac{\Gamma_\tau}{2\Gamma}} e^{i\omega x} e^{-\frac{|x|^2 \Gamma_\tau}{2}},
\]

where $\Gamma_\tau = \delta/c$ is the crossing time, the time it takes for a raising widened quantum level to cross the Fermi level, $\tau_D = \hbar/(2\delta)$ is the dwell time, an average time spent an electron on a quantum level before escaping to the Fermi sea provided that such an escape is possible, that is, after the quantum level has risen above the Fermi level. Note that if $\tau_D \ll \Gamma_\tau$, then $\psi(\omega)$, Eq. (6), is essentially $\psi_L$, Eq. (4). Notice, to get a stream of electrons we need a set of levels. Subsequent crossings occur with a delay of $T_0 \gg \Gamma_\tau, \tau_D$. Now equations (1) and (6) give us,

\[
\mathcal{P}^{ex}_{auto}(\omega) = \frac{e^2}{T_0} e^{-|\omega|^2 \Gamma_\tau},
\]

\[
\mathcal{P}^{c}_{cross}(\omega) = -\frac{e^2}{T_0} \frac{1}{1 + (\omega \tau_D)^2}.
\]

For this model, the crossing time $2\Gamma_\tau$ is the only parameter that determines the exponential energy distribution, the same as for the source of levitons. \(43\). This is why the auto-correlation noise is the same as in the first example.

However, the shape of the wave packet is different from that of a leviton. Namely, if the dwell time is comparable with the crossing time, $\tau_D \gtrsim \Gamma_\tau$, the density profile becomes larger than $2\Gamma_\tau$, asymmetric, and with some wavy structure developing at later times. All this leads to additional suppression of $N(\omega)$ and $\mathcal{P}^{c}_{cross}(\omega)$ with increasing frequency. In the case when $\tau_D \gg \Gamma_\tau$, the dwell time, not the crossing time determines how the cross-correlation noise decreases with frequency. The dwell time does not affect $\mathcal{P}^{ex}_{auto}(\omega)$, because energy does not change during tunneling.

The connection between the auto-correlation noise and energy becomes even more transparent in the final example, where the dwell time is the only characteristic time.

The last, third example is injection from a quantum dot with the equidistant ladder of levels, which is suddenly raised by one level spacing $\Delta$ at $t = 0$. \(31\) \(44\) The Fermi level is exactly between the two successive levels. The probability of tunneling between the dot and


the Fermi sea is small. The wave function, \( \psi^\Delta(t) = e^{-\frac{i}{\hbar} \mu t} \psi^\Delta(t) \), has an envelope\(^{35,45} \)

\[
\psi^\Delta(t) = \theta(t) \frac{e^{-i\omega_0 t}}{\sqrt{\tau D}} e^{-\frac{\mu t}{\tau D}}. \tag{8}
\]

Here \( \theta(t) \) is the Heaviside step function and \( \hbar \omega_0 = \Delta/2 \). Notice, in this case, the wave packet width is determined by the dwell time, while the energy of an injected electron is \( \hbar \omega_0 \), which is unrelated to \( \tau_D \).

For not too large frequencies, \( \omega \ll \Delta/\hbar \), the straightforward calculations lead to (see Appendix A for details)

\[
\begin{align*}
P_{\text{auto}}^{\alpha\alpha}(\omega) & = R \frac{e^2}{T_0}, \\
P_{\text{cross}}^{\alpha\alpha}(\omega) & = -R \frac{e^2}{T_0} \frac{1}{1 + (\omega \tau_D)^2}.
\end{align*}
\]

Since the particles are injected far above the Fermi sea, \( \Delta/2 \gg \hbar \omega_0 \), all of them contribute to noise. As a result, there is no energy related suppression. Therefore, the auto-correlation noise is independent on frequency. On the other hand, the density profile has a finite width, \( \tau_D \). Therefore, the cross-correlation noise gets suppressed at \( \omega \geq \tau_D^{-1} \).

One more important conclusion can be drawn from Eq. (1). If a single-particle envelope wave function, \( \psi \), is real-valued, for example, as in the case of a Majorana fermion\(^{46,47} \), its contribution to the auto-correlation noise is identically zero in the weak backscattering regime. It is also equal to zero if there is no wave splitter at all (\( R = 1 \) in the present notation).\(^{48} \)

It worth to be mentioned, the charge conservation implies \( P_{\text{auto}}^{\alpha\alpha}(0) + P_{\text{cross}}^{\alpha\alpha}(0) = 0, \)\(^{14} \) which can be proven for Eq. (1) using the Kramers-Kronig relations and normalization of the wave function, \( \int dt |\psi(t)|^2 = 1 \). This fact imposes some indirect constraint on the wave function of a single-electron wave packet that can be injected into a one-dimensional Fermi sea. In particular, no a single particle with a real (scalar) wave function can be injected in a clean manner, that is, without accompanying electron-hole pairs. Indeed, as the equation (1) predicts, the cross-correlation noise at zero frequency is not zero, \( P_{\text{cross}}^{\alpha\alpha}(0) = -Re^2/T_0 \neq 0 \). While in the case of a real-valued wave function, the excess auto-correlation noise vanishes for any frequency is zero, \( P_{\text{auto}}^{\alpha\alpha}(\omega) = 0 \).

To resolve seeming violation of the charge conservation, we must assume that if such a particle is injected, then the additional excitations are unavoidable created. The example is a half-leviton\(^{49} \), a particle with a real wave function whose creation is accompanied by the creation of an electron-hole cloud.

The rest of a paper is structured as follows. In Sec. II the connection between the electrical current correlation functions, the auto- and cross-correlation noise power and the first-order correlation function of the periodic stream of electrons injected into a chiral conductor is established within the framework of the Floquet scattering matrix approach. Such a general connection allows for a detailed analysis of the similarities and differences between the auto- and cross-correlation noise, which is illustrated in Sec. III using some examples. The conclusion is given in Sec. IV. Some technical details of calculations are presented in Appendices A - D.

## II. ELECTRICAL NOISE AND ELECTRON CORRELATION FUNCTION

To drive a current through a conductor, some external source is needed. The role of the source can be played, for example, by a constant or time-dependent voltage applied across a conductor, a time-dependent gate voltage, which changes the position of the quantum levels of electrons in the conductor or in its part, etc. If the characteristics of the source are known, the current can be calculated. In the quantum coherent regime, when the current is carried by individual electrons, the characteristics of carriers, for example, their wave function, are also can be calculated using the characteristics of the source. The measurements of electrical current and its fluctuations were already used to acquire information on quantum state of carriers.\(^{1,2,15} \) Therefore, it is desirable to have a direct relation between the electrical and electron characteristics without explicit recursion to the characteristics of the source. Some efforts in this direction have already been made.\(^{43,50,51} \) Below the fluctuations of an electrical current are expressed in terms of the wave functions, more precisely, in terms of the excess first-order correlation function\(^{17,18,35,45} \) of electrons responsible for those fluctuations.

To be specific, here I am interested in a quantum-coherent conductor connected via one-channel (chiral) leads\(^{52} \) to several electron reservoirs in equilibrium. Some (or all) incoming leads are fed by external sources working periodically with period \( T_0 \).

### A. Frequency-dependent noise

The correlation function of currents, \( I_\alpha, I_{\alpha'} \), flowing in leads \( \alpha \) and \( \alpha' \) of a multi-terminal conductor is defined as follows,\(^{14} \)

\[
P_{\alpha\alpha'}(\omega) = \int_{-T_0/2}^{T_0/2} dt \int_{-\infty}^{\infty} d\tau e^{i\omega \tau} \left\{ -I_\alpha(t+\tau)I_{\alpha'}(t) \right\}. \tag{10}
\]

where \( \hat{I}_\alpha \) and \( I_\alpha = \langle \hat{I}_\alpha \rangle \) are an operator in second quantization and a corresponding measurable for a current in
the lead $\alpha$; the angular brackets $\langle \ldots \rangle$ denote the quantum statistical average; for a periodic drive, $T_0$ is a period, for a non-periodic drive $T_0 \to \infty$.

The current operator $\hat{I}_\alpha$ is expressed in terms of creation and annihilation operators $\hat{a}_\alpha^\dagger(E)$, $\hat{a}_\alpha(E)$ of electrons with energy $E$ incoming from the reservoir $\alpha$ and operators $\hat{b}_\alpha^\dagger(E)$, $\hat{b}_\alpha(E)$ of electrons with energy $E$ scattered into the reservoir $\alpha$.\textsuperscript{53} In the wide band limit, that is, when the relevant energy scales, such as a voltage applied, a temperature, the energy quantum $\hbar$ with $\Omega = 2\pi/T_0$, etc., are all small compared to the Fermi energy $\mu_\alpha$, the current operator reads, $\textsuperscript{54}$

$$\hat{I}_\alpha(t) = \frac{e}{\hbar} \int dE dE' e^{i\frac{E-E'}{\hbar}t} \times \left\{ \hat{b}_\alpha^\dagger(E') \hat{a}_\alpha(E') - \hat{a}_\alpha^\dagger(E') \hat{a}_\alpha(E') \right\}. \quad (11)$$

In the case of a periodically driven conductor, the operators $\hat{b}_\alpha$ are related to various operators $\hat{a}_\alpha$ via the elements of the unitary Floquet scattering matrix $S_F$, $\textsuperscript{55}$

$$\hat{b}_\alpha(E) = \sum_\beta \sum_{n=-\infty}^{\infty} S_{F,\alpha\beta}(E_n, E) \hat{a}_\beta(E_n), \quad (12)$$

where I introduced a short notation $E_n = E + n\hbar\Omega$.

Charge conservation requires the scattering matrix to be unitary, which means,

$$\sum_\gamma \sum_{n=-\infty}^{\infty} S_{F,\gamma\alpha}^*(E_n, E_m) S_{F,\gamma\beta}(E_n, E) = \delta_{\alpha\beta}\delta_{mn,0}, \quad (13a)$$

$$\sum_\gamma \sum_{n=-\infty}^{\infty} S_{F,\alpha\gamma}^*(E_m, E_n) S_{F,\beta\gamma}(E, E_n) = \delta_{\alpha\beta}\delta_{mn,0}, \quad (13b)$$

where $\delta_{mn,0}$ is the Kronecker delta.

Equation (12) allows to express the quantum-statistical average of the product of $b-$operators in terms of that of $a-$operators. Because the reservoirs are in equilibrium, the latter average is known. In the case of reservoirs of non-interacting electrons forming the Fermi sea, we have $\langle \hat{a}_\beta^\dagger(E) \hat{a}_\beta(E') \rangle = f_\beta(E) \delta(E - E')$, where $f_\beta(E)$ is the Fermi distribution function with temperature $\theta_\beta$ and chemical potential $\mu_\beta$, and $\delta(E - E')$ is the Dirac delta.

1. $2 \times 2$ circuit

Our aim is to compare auto- and cross-correlation noise. The minimal circuit that allows cross-correlation noise is an electronic wave splitter, a quantum point contact (QPC) with two incoming, $\beta = 1, 2$, and two outgoing, $\alpha = 3, 4$, channels, see Fig. 1.

Below I am interested in current fluctuations in outgoing channels, that is, $\alpha, \alpha' = 3, 4$ in Eq. (10). For this case, the general equation for noise within the Floquet scattering matrix approach\textsuperscript{56,57} gives us,

$$\mathcal{P}_{33}(\omega) = \frac{e^2}{\hbar} \int dE \sum_{n,m,q=-\infty}^{\infty} 2 \sum_{\delta=1}^{2} \sum_{\gamma=1}^{2} F_{\gamma\delta}(E_q + \hbar\omega, E) S_{F,\gamma\delta}^*(E_n, E) S_{F,\gamma\delta}(E_m, E) \times S_{F,\gamma\delta}^*(E_m + \hbar\omega, E_q + \hbar\omega) S_{F,\gamma\delta}(E_n + \hbar\omega, E_q + \hbar\omega), \quad (14a)$$

and

$$\mathcal{P}_{34}(\omega) = \frac{e^2}{\hbar} \int dE \sum_{n,m,q=-\infty}^{\infty} 2 \sum_{\delta=1}^{2} \sum_{\gamma=1}^{2} F_{\gamma\delta}(E_q + \hbar\omega, E) S_{F,3\delta}^*(E_n, E) S_{F,4\delta}(E_m, E) \times S_{F,4\gamma}^*(E_m + \hbar\omega, E_q + \hbar\omega) S_{F,3\gamma}(E_n + \hbar\omega, E_q + \hbar\omega), \quad (14b)$$

with

$$F_{\gamma\delta}(E_1, E) = \frac{f_\gamma(E_1) + f_\delta(E)}{2} - f_\gamma(E_1) f_\delta(E). \quad (15)$$

Let us also introduce excess noise, that is, an increase in noise due to the source, which is defined as the following difference

$$\mathcal{P}^{ex}_{\alpha\alpha'}(\omega) = \mathcal{P}_{\alpha\alpha'}(\omega) - \mathcal{P}^{off}_{\alpha\alpha'}(\omega), \quad (16)$$

where the upper index $off$ indicates that the source is off.

I suppose a unitary $2 \times 2$ scattering matrix of the QPC to be energy-independent,

$$S_{QPC} = \left( \begin{array}{cc} \sqrt{R} & i\sqrt{T} \\ i\sqrt{T} & \sqrt{R} \end{array} \right), \quad (17)$$

a real number $0 \leq R \leq 1$ is the reflection probability, the transmission probability $T = 1 - R$. We need an energy independent $S_{QPC}$ to use the noise to get information
on injected wave packets only. If the properties of the electronic circuit that connects the incoming and outgoing channels depend on energy, the outgoing signal also carries nontrivial information about this circuit.\textsuperscript{58}

In addition, for the sake of simplicity, I suppose that the periodic source is present only in the incoming channel $\beta = 1$. It is characterized by the Floquet scattering amplitude, which is a matrix in an energy space with elements $S_F(E, E_n)$. The results presented below can be directly generalized to the case when another source is added in the second incoming channel, see Appendix B.\textsuperscript{4}

For the circuit with single source and single QPC, the elements of the total Floquet scattering matrix are represented as follows,

\[
S_{F,31}(E, E_n) = \sqrt{R} S_F(E, E_n), \\
S_{F,41}(E, E_n) = i\sqrt{T} S_F(E, E_n), \\
S_{F,32}(E, E_n) = i\sqrt{T} \delta_{n,0}, \\
S_{F,42}(E, E_n) = \sqrt{R} \delta_{n,0}.
\]

All other elements are zero.

### B. First-order correlation function

To characterize a quantum state injected by the source into a ballistic one-dimensional electronic waveguide, I use the first-order correlation function, $G^{(1)}$. This function is defined as a quantum statistical average of the product of two field operators for electrons calculated in the electronic wave-guide $\beta$ just after the source,

\[
G^{(1)}_{\beta}(t_1; t_2) = \langle \hat{\Psi}^\dagger_{\beta}(t_1) \hat{\Psi}_{\beta}(t_2) \rangle.\textsuperscript{17}
\]

Strictly speaking, this object is a $2 \times 2$ matrix in the spin space. However, here I consider the spin-polarized case and suppress the spin index.

In the case under consideration, the source is placed in lead $\beta = 1$ and it is characterized by the Floquet scattering amplitude, $S_F(E_n, E)$. The corresponding correlation function is calculated as follows,\textsuperscript{50}

\[
v_\mu G^{(1)}_{\mu,\beta}(t + \tau; t) = \frac{1}{\hbar} \int dE f_\mu(E) e^{ie^{it} \tau} \sum_{n,m=-\infty}^{\infty} e^{im\tau} \\
\times e^{i\Omega(n-m)t} S_F^* (E_n, E) S_F (E_m, E). \tag{19}
\]

Here $v_\mu$ is a velocity of electrons at the Fermi level, which is originated from the density of states being energy independent in the wide band limit used here.

When the source is switched off, $S_F(E_n, E) = \delta_{n,0}$, the above equation is reduced to the correlation function of the Fermi sea in equilibrium, $G^{(1)}_{\mu,\beta}(t + \tau; t) \equiv G^{(1)}_{\mu,\beta}(\tau)$.

\[
v_\mu G^{(1)}_{\mu,\beta}(\tau) = \frac{1}{\hbar} \int dE f_\mu(E) e^{i\frac{\pi}{\hbar} \tau} = e^{i\frac{\pi}{\hbar} \tau} \frac{1}{2\pi i} \frac{1}{\sinh \left( \tau/\tau_\theta \right)}. \tag{20}
\]

Here $\tau_\theta = \hbar/(\pi k_B T_\theta)$ is the thermal coherence time for the reservoir, where the lead $\beta$ is attached to.

The difference of correlation functions with the source being on and off is the excess correlation function, which characterizes what is injected by the source into an electron waveguide $\beta = 1$,

\[
G^{(1)}_{\mu,\beta}(t_1; t_2) = G^{(1)}_{\mu,\beta}(t_1; t_2) - G^{(1)}_{\mu,0}(t_1 - t_2). \tag{21}
\]

In the case when the source injects a single electron with wave function $\Psi(t)$ per period, the excess correlation function during that period takes on a very simple form.

\[
G^{(1)}_{\mu,\beta}(t_1; t_2) = \Psi^*(t_1) \Psi(t_2). \tag{22a}
\]

In the case of a multi-particle injection $G^{(1)}_{\mu,\beta}(t_1; t_2) = \sum_j \Psi_j^*(t_1) \Psi_j(t_2). \tag{22b}$

### C. Noise power in terms of $G^{(1)}$

In the case of non-interacting electrons, the correlation function $G^{(1)}$ contains complete information about the system of electrons. In particular, all measurable can be expressed in terms of correlation function, see, e.g., Ref. 50 for some examples. Such expressions are notably useful when transport is due to only a few electrons per period.

Here I express the excess noise in terms of $G^{(1)}$ in the case when all incoming channels have the same temperature $\theta_\beta = \theta$ and Fermi energy $\mu_\beta = \mu$. Therefore, the equilibrium electronic correlation functions are the same, $G^{(1)}_{0,\beta} = G^{(1)}_0$. For more general case and for details of calculations, see Appendix B.

First, let us substitute Eqs. (18) and (15) into Eqs. (14) and calculate the excess noise, Eq. (16). Then let us separate linear and bilinear in Fermi functions terms. The former ones are nullified, while the lather ones are expressed in terms of the correlation functions presented in Eqs. (19), (20), and (21). As a result, I find for the auto-correlation noise, [see Eq. (B16)]

\[
\mathcal{P}^{xx}_{55}(\omega) = e^{2}v^2 \int dt e^{i\omega t} \int -\tau_{\omega}/2 -\tau_{\omega}/2 dt e^{i\omega t} \left\{ \begin{array}{l} \\
\left[ G^{(1)}_1(t + \tau; t) \right]^2 \\
-2R \text{Re} G^{(1)}_1(t + \tau; t) G^{(1)*}_0(\tau) \end{array} \right\}. \tag{22a}
\]
and for the cross-correlation noise, [see Eq. (B20)]

\[
P_{34}(\omega) = -RT e^{2} v_{\mu}^{2} \int_{-\tau_{0}/2}^{\tau_{0}/2} \frac{dt}{T_{0}} \int_{-\infty}^{\infty} d\tau e^{i \omega \tau}
\times \left| G_{1}^{(1)} (t + \tau; t) \right|^{2}.
\]

Notice that when all reservoirs are in the same conditions, cross-correlation noise disappears when the source is turned off. This is why the superscript \text{ex} is omitted.

The important difference between auto- and cross-correlation noise, Eqs. (22a) and (22b), is that the latter one is determined solely by what is injected by the source, while the former one in addition depends explicitly on the properties of the Fermi sea.

The part of the noise that is determined by \[ G_{1}^{(1)} \] depends on the possible quantum exchange\textsuperscript{14} between the injected electrons. At zero temperature and when electrons are injected one at a time without overlapping, this part of the noise is reduced to the product of currents in Eq. (10). In the wide band approximation used here, the electric current is proportional to the density profile of the wave packet, hence Eq. (1), the second line.

In contrast, the part of the noise that is determined by the product of \[ G_{1}^{(1)} \] and \[ G_{0}^{(1)} \] takes into account the quantum exchange of an injected electron and electrons of the Fermi sea. Such an exchange does not contribute to cross-correlation noise, unless the two incoming Fermi seas are different, see Eq. (B19).

The formal difference between the auto- and cross-correlation noise becomes especially pronounced in the weak back-scattering regime, \( R \ll 1 \), when

\[
P_{33}(\omega) = -RT e^{2} v_{\mu}^{2} \int_{-\tau_{0}/2}^{\tau_{0}/2} \frac{dt}{T_{0}} \int_{-\infty}^{\infty} d\tau e^{i \omega \tau} \left| 2 \text{Re} G_{1}^{(1)} (t + \tau; t) G_{0}^{(1)*} (\tau) \right|,
\]

\[
P_{34}(\omega) = -RT e^{2} v_{\mu}^{2} \int_{-\tau_{0}/2}^{\tau_{0}/2} \frac{dt}{T_{0}} \int_{-\infty}^{\infty} d\tau e^{i \omega \tau} \left| G_{1}^{(1)} (t + \tau; t) \right|^{2}.
\]

Using Eq. (20) for \( G_{0}^{(1)} \) at zero temperature, \( \theta = 0 \Rightarrow \tau_{0} \to \infty \), and for a single-particle injection, \( G_{1}^{(1)} (t + \tau; t) = e^{i \frac{\tau}{\tau_{0}} \psi^{*} (t + \psi) \psi (t)} \), I arrive at Eq. (1) with \( P_{33}^{\text{ex auto}} = P_{33}^{\text{ex}} \) and \( P_{34}^{\text{cross}} = P_{34} \), where the integration over \( t \) is extended to infinity, because the duration of wave packet is much less than the period \( T_{0} \).

III. EXAMPLES

Here I will consider two examples: one when auto- and cross-correlation noise are perfectly anti-correlated at any frequency, and the other when they can be different.

A. Energy-independent source

In the case when the properties of the source do not change on the scale of the energy of the injected particles, the corresponding Floquet scattering amplitude can be represented as a Fourier coefficient of a certain energy-independent scattering amplitude, \( S_{E} (E_{n}, E) = \int_{0}^{T_{0}} dt e^{i \omega t} e^{-\frac{\pi}{\hbar} \theta_{0}} S(t) \).\textsuperscript{45,55} In a one-dimensional case, unitarity implies that \( S(t) \) is a pure phase factor, that is, \( |S(t)|^{2} = 1 \). For example, if a voltage \( V(t) \) plays a role of a source, then it is \( S(t) = \exp \left( i \frac{\pi}{\hbar} \int_{t}^{t'} dt' V(t') \right) \).

In such a case, equation (19) gives us, \( G_{1}^{(1)} (t_{1}; t_{2}) = S^{*} (t_{1}) S(t_{2}) G_{0_{01}}^{(1)} (t_{1} - t_{2}) \). Remind that \( G_{001}^{(1)} \) describes the Fermi sea in equilibrium at temperature \( \theta \). Using this result in Eqs. (22) and taking into account that

\[
G_{1}^{(1)} (t_{1}; t_{2}) = \{ S^{*} (t_{1}) S(t_{2}) - 1 \} G_{001}^{(1)} (t_{1} - t_{2}),
\]

I find that the excess auto- and cross-correlation noise are perfectly anti-correlated at any frequency,

\[
P_{33}^{\text{ex}} (\omega) + P_{34} (\omega) = 0,
\]

not only at zero frequency, \( \omega = 0 \), as the charge conservation requires\textsuperscript{14}, see also Appendix B.3. An example was shown in Eq. (5).

For \( R = 1 \), when cross-correlation noise does not exist, that is, formally \( P_{34} = 0 \), the above equation tells us that whatever emitted by the source under consideration is silent on any frequency, the excess auto-correlation noise is zero, \( P_{33}^{\text{ex}} (\omega) = 0 \). In particular, any voltage applied to the ballistic channel produces no excess noise at any frequency. Note that for a generic source injecting electrons into a ballistic waveguide, a similar conclusion can be drawn for noise only at zero frequency, see Eq. (B21).

Some general conclusions can be made regarding the effect of temperature on noise. Indeed, the equations (24) and (20) allow us to relate the excess correlation function at zero (the extra subscript 0) and non-zero (the extra subscript \( \theta \)) temperatures,

\[
G_{1,0}^{(1)} (t + \tau; t) = \frac{\tau / \tau_{0}}{\sinh (\tau / \tau_{0})} G_{1}^{(1)} (t + \tau; t).
\]

Then I use the above equation in Eqs. (22), utilize the
inverse Fourier transformation with respect to $\omega$ and express the noise at temperature $\theta$, $\mathcal{P}_0^{ex}$, in terms of the noise at zero temperature, $\mathcal{P}_0^{ex}$, as follows,

$$\mathcal{P}_0^{ex}(\omega) = \int_{-\infty}^{\infty} d\tau e^{i\omega \tau} \left( \frac{\tau / \tau_0}{\sinh (\tau / \tau_0)} \right)^2 \int_{-\infty}^{\infty} d\omega' \frac{2}{2\pi} e^{-i\omega' \tau} \mathcal{P}_0^{ex}(\omega').$$

(27)

Here I introduce $\mathcal{P}^{ex} \equiv \mathcal{P}_3^{ex} = -\mathcal{P}_{34}$ according to Eq. (25).

B. Injection from a quantum level raising at a constant rapidity

Now let us consider a single-electron injection from a source, whose properties do depend on energy. The corresponding scattering amplitude and the wave function of the injected electron were discussed in Ref. 42 at zero temperature and in Ref. 59 at nonzero temperatures. In this case, the auto- and cross-correlation noises don’t stick together unless at zero frequency.

At zero temperature, the excess correlation function is $\nu_n(G_1^{(1)}(t + \tau; t) = e^{i\pi/2} \psi^{(c)\ast}(t + \tau) \psi^{(c)}(t)$, where $\psi^{(c)}$ is shown in Eq. (6). Using this equation in Eqs. (22) and assuming that the width of the wave packet is small compared to the period, $\Gamma_\tau \ll \tau_0$, I find, (see Appendix C for details)

$$\mathcal{P}_{33}^{ex}(\omega) = \frac{R \epsilon^2}{\tau_0 1 + (\omega \tau_D)^2} e^{-|\omega|2\Gamma_\tau},$$

$$\mathcal{P}_{34}(\omega) = -\frac{R \epsilon^2}{\tau_0 1 + (\omega \tau_D)^2} e^{-|\omega|2\Gamma_\tau}.$$  

(28)

At $R \ll 1$ ($T \approx 1$) we reproduce Eq. (7).

At non-zero temperature, auto- and cross-correlation noise are modified by the same factor, (see Appendix D for details),

$$\eta(\omega, \theta) = e^{i\omega 2\Gamma_\tau} \int_{-\infty}^{\infty} \frac{dx}{\pi} \frac{e^{ix\omega 2\Gamma_\tau}}{x^2 + 1} \left( \frac{x 2\Gamma_\tau / \theta}{\sinh (x 2\Gamma_\tau / \theta)} \right)^2$$

(29)

Interestingly, the above equation is independent of the dwell time $\tau_D = \hbar / (2\Gamma_\tau c)$, where $c$ is a rapidity, see Eq. (6). Therefore, the same factor $\eta(\omega, \theta)$ applies for the case of $\tau_D = 0$, which is the case for the source of levitons of half-width $\Gamma_\tau$. However this analogy is not complete.

Namely, for levitons the high-temperature noise can be expressed directly in terms of the noise at zero temperature, see Eq. (27). On the contrary, for electrons emitted from the quantum level, this is generally not the case due to factors depending on $\omega \tau_D$. Yet, in the weak backscattering regime, $R \ll 1$, the auto-correlation noise obeys Eq. (27), because it does not depend on $\tau_D$, see Eq. (7).

The temperature-dependent factor $\eta(\omega, \theta)$, Eq. (29), is shown in Fig. 2 for several frequencies $\omega$. Remarkably, the maximum occurs at $\omega \tau_D \sim 1$, which is independent of properties of the source. The non-monotonic temperature behavior at non-zero frequencies is due to two counter acting effects, both due to the fact that the quantum state of electrons injected at non-zero temperatures is a mixed quantum state.\textsuperscript{50}

The first effect, which leads to noise suppression, comes from the fact that each component of a mixed state is scattered independently at the wave splitter. Such an independent scattering manifests itself as second order coherence.\textsuperscript{60} As a result, the effect of charge quantization becomes less pronounced, and shot noise decreases with increasing temperature. At $\theta \gg \theta_0$, where $k_B \theta_0 = \hbar / (2\pi \Gamma_\tau)$, the shot noise decays as $\theta_0 / \theta$.\textsuperscript{61}

Suppression of a zero-frequency shot noise with temperature has been reported in Refs. 3,7,62,63. For the source of levitons, this effect was predicted in Ref. 19.

The second effect, leading to an increase in noise, is associated with an effective broadening of the energy distribution of injected particles caused by broadening of the probability density for the components of mixed state with increasing temperature, $p(\epsilon) = -\partial f_1(\epsilon)/\partial \epsilon$, see Eq. (D1). As a result, the injected particle is more likely to be able to emit energy $\hbar \omega$ in order to contribute to noise at frequency $\omega$.\textsuperscript{9} This increase reaches saturation at $4k_B \theta \sim \hbar \omega$, which leads to the maxima in Fig. 2.
IV. CONCLUSION

The finite-frequency fluctuations of an electric current in multi-terminal conductors were analyzed at zero as well as non-zero temperatures. The focus was on the quantum coherent regime, when the current is carried by non-overlapping single-particle wave packets periodically injected into a unidirectional, chiral wave guide.

To highlight similarities and differences between auto- and cross-correlation noise, the fluctuations of an electric current were expressed in terms of the wave functions of injected electrons, bypassing the use of explicit source characteristics. Two contributions to shot noise have been identified. The first, which depends on the possible quantum exchange between the injected electrons, determines the cross-correlation noise and part of the auto-correlation noise. In the case of single-particle injection and at zero temperature, this part is determined by the density profile of the injected wave packets. The second contribution, which depends on the quantum exchange of an injected electron and electrons of the Fermi sea, contributes only to the auto-correlation noise. This part is determined by the coherence of the injected wave packets multiplied by the coherence of the Fermi sea.

At zero frequency, the charge conservation tightly links both contributions to shot noise. Such a connection allows us to make some general conclusions related to the properties of excitations that can be injected/created in the Fermi sea. In particular, no excitations with a real density profile of the injected wave packets. The second contribution, which depends on the quantum exchange of an injected electron and electrons of the Fermi sea, contributes only to the auto-correlation noise. This part is determined by the coherence of the injected wave packets multiplied by the coherence of the Fermi sea.

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For several experimentally available single-electron sources for which the wave function was calculated, I compared auto- and cross-correlation noise. For the family of so-called energy-independent sources, the source of leviton is an example, the contribution related to the density profile and the contribution related to the coherence of the wave packet turn out to be the same, see Eq. (5). So, the auto- and cross-correlation noises are the same (up to the minus sign) at any frequency not only at zero frequency as the charge conservation requires, see Eq. (25). For another source, which relies on tunneling, the two contributions are manifestly different, see Eqs. (7) and (9) for different working regimes of the source.

I analyzed the effect of temperature on shot noise in the case when electrons are injected on top of the Fermi. It turns out that temperature affects both contributions equally, see Eq. (29) for the temperature-dependent factor. Since one of the contributions to shot noise depends on the quantum state of electrons in the Fermi sea, I conclude that temperature affects the quantum state of both the electrons in the Fermi sea and the injected electrons in the same way. Namely, a pure state at zero temperature becomes a mixed state at non-zero temperatures. At zero frequency, changing the quantum state from pure to mixed leads to noise suppression, while at non-zero frequencies, the temperature dependence of noise is non-monotonic, see Fig. 2. The temperature-dependent factor peaks when the thermal coherence time becomes of the order of the inverse of the frequency at which the noise is measured. Importantly, the position of this maximum does not depend on the properties of the sources under consideration.

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Appendix A: Auto-correlation noise from Eq. (9)

After substituting Eq. (8) into Eq. (1), the first line, I get,

$$\mathcal{P}_{\text{auto}}^{ex}(\omega) = \frac{e^2}{\hbar^2} \int_0^\infty dt \int_\tau^\infty \frac{d\tau}{\tau \cdot \tau_D} \sin \left( \frac{\omega \tau}{\pi \tau_D} \right) e^{-\frac{t + \tau}{\tau_D}}.$$

(A1)

To integrate with respect to $t$, I split the integration area into two and interchange the order of integration,

$$\int_0^\infty dt \int_\tau^\infty d\tau = \int_\tau^\infty d\tau \int_0^\infty dt - \int_\tau^\infty d\tau \int_0^\infty dt.$$

Then I have,

$$\mathcal{P}_{\text{auto}}^{ex}(\omega) = \frac{e^2}{\hbar^2} \eta(\omega),$$

(A2)

$$\eta(\omega) = \int_0^\infty d\tau \cos \left( \omega \frac{\tau}{\tau_D} \right) e^{-\frac{\tau}{\tau_D}} \frac{2 \sin \left( \omega \tau \right)}{\pi \tau_D}.$$

The suppression factor $\eta(\omega)$ is shown in Fig. 3. Let us first consider the case of $\omega = 0$, when
order \( \tau_D^{-1} \) near \( \omega = \omega_0 \) (that is, near \( h\omega = \Delta/2 \)) in full agreement with the previous findings.\(^9,64\) Here I demonstrated that the wave function \( \psi^\Delta(t) \), Eq. (8), carries information about this noise suppression effect.

The calculations leading from Eq. (1), the second line with the wave function from Eq. (8), to Eq. (9), the second line, are rather straightforward. Importantly, the cross-correlation noise gets suppressed at much smaller frequencies of order \( \tau_D^{-1} \ll \omega_0 \).

### Appendix B: Relation between an electrical noise and an electron correlation function

Here I generalize the results of Sec. II C. For this, it is convenient to separate the terms linear and bilinear in the Fermi functions \( f_1 \) and \( f_2 \) in Eqs. (14). I will distinguish such terms via the upper index \( l \) and \( b \), respectively,

\[
\mathcal{P}_{33}^l(\omega) = e^2 \hbar \int dE F_{33}(E, E + h\omega) + \sum_{n,m,q=\infty} \mathcal{P}_{33}^b(\omega),
\]

\[
\mathcal{P}_{34}^l(\omega) = \mathcal{P}_{34}^b(\omega).
\]

#### 1. Auto-correlation nose

Let us first consider \( \mathcal{P}_{33} \). Substituting Eq. (18) into Eq. (14), I find

\[
\mathcal{P}_{33}(\omega) = e^2 \hbar \int dE \left\{ F_{33}(E, E + h\omega) + \sum_{n,m,q=-\infty} R^2 f_{11}(E_q + h\omega, E) S_F^l(E_{m,n}, E) S_F(E_{m,n}, E) \times S_F^l(E_{m+n+\omega_0}, E) S_F(E_{m+n+\omega_0}, E) \right\}.
\]

Then, I use Eq. (15) and calculate a linear in Fermi functions \( f_1 \) and \( f_2 \) part,

\[
\mathcal{P}_{33}^l(\omega) = e^2 \hbar \int dE \left\{ R f_1(E) + R f_1(E + h\omega) + T f_2(E) + T f_2(E + h\omega) \right\}.
\]
In the course of calculations, I utilized unitarity of the Floquet scattering matrix, see Eq. (13). For a single-channel $S_F$, unitarity implies the following,

$$
\sum_{n=-\infty}^{\infty} S_F^*(E_n, E_m) S_F(E_n, E) = \delta_{m,0}. \quad (B4)
$$

As an example, let us consider the very first term we need to calculate,

$$
e^2/2\hbar \int dE \sum_{n,m,q=-\infty}^{\infty} R^2 f_1(E_q + \hbar \omega) S_F^*(E_n, E_q) S_F(E_m, E_q) \times S_F^*(E_m + \hbar \omega, E_q + \hbar \omega) S_F(E_n + \hbar \omega, E_q + \hbar \omega). \quad (B5)
$$

To simplify it, I shift $E_q \rightarrow E$ under integration over energy and shift $q \rightarrow -q$, $n-q \rightarrow n$, $m-q \rightarrow m$ under the corresponding sums,

$$
e^2/2\hbar \int dE \sum_{n,m,q=-\infty}^{\infty} R^2 f_1(E + \hbar \omega) S_F^*(E_n, E_q) S_F(E_m, E_q) \times S_F^*(E_m + \hbar \omega, E + \hbar \omega) S_F(E_n + \hbar \omega, E + \hbar \omega). \quad (B6)
$$

Then, the sum over $q$ gives us, $\sum_q S_F^*(E_n, E_q) S_F(E_m, E_q) = \delta_{n,m}$, which is used to sum over, say, $m$. The remaining sum over $n$ gives $\sum_n |S_F(E_n + \hbar \omega, E + \hbar \omega)|^2 = 1$. Therefore, what left is $e^2/2\pi \int_0^{\infty} dE R^2 f_1(E + \hbar \omega)$. Other terms are calculated by analogy.

The bilinear in Fermi functions $f_1$ and $f_2$ part reads,

$$
P_{33}^b(\omega) = -e^2/\hbar \int dE \sum_{n,m,q=-\infty}^{\infty} \left\{ \right. \nonumber \left. \right.

R^2 f_1(E_q + \hbar \omega) f_1(E) S_F^*(E_n, E) S_F(E_m, E) \\
\times S_F^*(E_m + \hbar \omega, E_q + \hbar \omega) S_F(E_n + \hbar \omega, E_q + \hbar \omega) \\
+ RT f_2(E_q + \hbar \omega) f_1(E) S_F^*(E_n, E) S_F(E_m, E) \delta_{mq} \delta_{nq} \\
+ TR f_1(E_q + \hbar \omega) f_2(E) S_F^*(E_n, E) S_F(E_m, E) \delta_{m0} \delta_{nq} \\
\times S_F^*(E_m + \hbar \omega, E_q + \hbar \omega) S_F(E_n + \hbar \omega, E_q + \hbar \omega) \\
+ T^2 f_2(E_q + \hbar \omega) f_2(E) \delta_{m0} \delta_{n0} \delta_{mq} \delta_{nq}. \quad (B5)
$$

Let us represent $P_{33}^b(\omega) = \sum_{j=1}^{4} B_j$ and calculate various terms separately. The first term is,

$$
B_1 = -e^2/\hbar \int dE \sum_{n,m,q=-\infty}^{\infty} R^2 f_1(E_q + \hbar \omega) f_1(E) S_F^*(E_n, E) S_F(E_m, E) \\
\times S_F^*(E_m + \hbar \omega, E_q + \hbar \omega) S_F(E_n + \hbar \omega, E_q + \hbar \omega) \\
\times \frac{\tau/2}{\tau_0/2} \\
\times \int_{-\tau_0/2}^{\tau_0/2} dt \int d\tau e^{i\omega\tau} \left| G_1^{(1)}(t + \tau, t) \right|^2, \quad (B6)
$$

where $G_1^{(1)}$ is the first-order correlation function of the Fermi sea incoming from the first channel and modified by the source, see Eq. (19). To prove the last line, I compute the time integral explicitly:

$$
\int_{-\tau_0/2}^{\tau_0/2} dt \int_{-\tau_0/2}^{\tau_0/2} d\tau e^{i\omega\tau} \int dE f_1(E) e^{-iE\tau} \sum_{n,m=-\infty}^{\infty} e^{-i\Omega n\tau} \\
\int_{-\tau_0/2}^{\tau_0/2} dt \int_{-\tau_0/2}^{\tau_0/2} d\tau e^{i\omega\tau} \int dE f_1(E') e^{iE'\tau} \sum_{n,m=-\infty}^{\infty} e^{-i\Omega n\tau} \\
\sum_{q,\ell=-\infty}^{\infty} e^{i\Omega q\tau} e^{i\Omega(q-\ell)\tau} S_F^*(E_q, E') S_F(E_{q-n}, E').
$$

The integration over $t$ gives $q - \ell = n - m$, which I use to sum up over $\ell = q - n + m$

$$
\int_{-\infty}^{\infty} dE f_1(E) e^{-iE\tau} \sum_{n,m,q=-\infty}^{\infty} e^{-i\Omega n\tau} \\
S_F(E_n, E) S_F^*(E_m, E) \int dE' f_1(E') e^{iE'\tau} e^{i\Omega n\tau} \\
S_F^*(E_q', E') S_F(E_{q-n}, E').
$$

The integration over $\tau$ gives $h\delta (\hbar \omega - E_n + E_q')$, which I use to integrate out $E_n = E_q' + \hbar \omega$,

$$
\sim f_1(E_{q-n} + \hbar \omega) f_1(E') S_F^*(E_{q-n}, E') S_F(E_{q-n+m}, E') \\
S_F^*(E_{q-n+m} + \hbar \omega, E_{q-n} + \hbar \omega) S_F(E_q' + \hbar \omega, E_{q-n} + \hbar \omega).
$$

Additionally I shift $q - n \rightarrow q$,

$$
\sim f_1(E_{q} + \hbar \omega) f_1(E') S_F^*(E_{q+n}, E') S_F(E_{q+m}, E') \\
S_F^*(E_{q+m} + \hbar \omega, E_{q} + \hbar \omega) S_F(E_{q+n} + \hbar \omega, E_{q} + \hbar \omega),
$$

and finally, I shift $q + n \rightarrow n$ and $q + m \rightarrow m$ and get the same integrand as in Eq. (B6) (up to $E' \rightarrow E$).
\[ \sim f_1(E_q + \hbar \omega) f_1(E') S_F^* (E_q', E') S_F (E_m', E') S_F^* (E_m + \hbar \omega, E_q + \hbar \omega) S_F (E_m + \hbar \omega, E_q' + \hbar \omega). \]

Other terms are calculated in the same way,

\[
B_2 = -\frac{e^2}{h} \int dE \sum_{q=\pm} \infty RT f_2(E_q + \hbar \omega) f_1(E) \times |S_F(E_q, E)|^2 = -RT v_\mu^2 e^2 \quad (B7)
\]

\[
\times \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int d\tau e^{i\omega \tau} G^{(1)}_1 (t + \tau; t) G^{(1)*}_{0,2} (\tau),
\]

\[
B_3 = -\frac{e^2}{h} \int dE \sum_{q=\pm} \infty TR f_1(E + \hbar \omega) f_2(E) \times |S_F(E + \hbar \omega, E_q + \hbar \omega)|^2 = -TR v_\mu^2 e^2 \quad (B8)
\]

\[
\times \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int d\tau e^{i\omega \tau} G^{(1)}_{0,2} (\tau) G^{(1)*}_1 (t + \tau; t),
\]

\[
B_4 = -\frac{e^2}{h} \int dE T^2 f_2(E + \hbar \omega) f_2(E)
\]

\[
= -T^2 v_\mu^2 e^2 \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int d\tau e^{i\omega \tau} \left| G^{(1)}_{0,2} (\tau) \right|^2. \quad (B9)
\]

Combing all terms together I get,

\[
\mathcal{P}_{33}^b (\omega) = -v_\mu^2 e^2 \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int d\tau e^{i\omega \tau} \left| R G^{(1)}_1 (t + \tau; t) + T G^{(1)}_{0,2} (\tau) \right|^2. \quad (B10)
\]

Note that when the second channel is also fed by a source, we need to replace the correlation function of the Fermi sea in equilibrium, \(G^{(1)}_{0,2}\), by the one modified by the source, \(G^{(1)}_1\).

Strictly speaking, the total autocorrelation noise, \(\mathcal{P}_{33}(\omega)\), Eq. (B1), diverges. This is due to the infinite number of electrons that make up the Fermi sea, which contribute to both \(\mathcal{P}_{33}^b(\omega)\), Eq. (B3), and \(\mathcal{P}_{33}^{off}(\omega)\), Eq. (B10). Therefore, to see the effect of injected electrons, we need to look at the excess noise. For this, I first calculate the noise when the source is off, \(\mathcal{P}_{33}^{off}\), and then calculate the excess noise as the difference, \(\mathcal{P}_{33}^{ex} = \mathcal{P}_{33} - \mathcal{P}_{33}^{off}\).

\[ a. \text{ Excess noise} \]

For the sake of simplicity, I assume all the reservoirs have the same Fermi energy, \(\mu_\alpha = \mu, \forall \alpha\). If necessary, the constant bias \(V_\alpha\) at lead \(\alpha\), that is, \(\mu_\alpha = \mu + eV_\alpha\), can be accounted for via an energy-independent scattering amplitude \(S_\lambda = e\frac{\hbar}{2} t\).

To calculate \(\mathcal{P}_{33}^{off}\), I replace \(G_1\) by \(G_{0,1}\) in Eq. (B10), use Eq. (B3), which remains unchanged, and get according to Eq. (B1),

\[
\mathcal{P}_{33}^{off} (\omega) = \frac{e^2}{h} \int dE \left\{ F_{33}(E, E + \hbar \omega) + R^2 F_{11}(E + \hbar \omega, E) + RT F_{21}(E + \hbar \omega, E) \right\}. \quad (B11)
\]

Then I transform,

\[
F_{\alpha\beta}(E, E + \hbar \omega) = F_{\alpha\alpha}(E, E + \hbar \omega) + F_{\beta\beta}(E, E + \hbar \omega) + \Phi_{\alpha\beta}
\]

\[
\Phi_{\alpha\beta} = [f_\alpha(E) - f_\beta(E)] [f_\alpha(E + \hbar \omega) - f_\beta(E + \hbar \omega)],
\]

and integrate over energy,

\[
\int dE F_{\alpha\alpha}(E, E + \hbar \omega) = \frac{\hbar \omega}{2} \coth \frac{\hbar \omega}{2k_B T},
\]

\[ \Xi(\theta_\omega, \theta_\beta, \omega) = \frac{1}{k_B (\theta_\alpha + \theta_\beta)} \int dE \Phi_{\alpha\beta} = \frac{2\theta_\alpha}{\theta_\alpha + \theta_\beta} \quad (B12) \]

\[
\times \int_0^1 dx \frac{x \left[ x\Omega \frac{\theta_\alpha}{\theta_\beta} - 1 \right] \left( \frac{x}{\Pi} \frac{\theta_\alpha}{\theta_\beta} - 1 \right) \left( \frac{x}{\Pi} \frac{\theta_\alpha}{\theta_\beta} - 1 \right) + \frac{\theta_\beta}{\theta_\alpha} \right] + T \theta_2 \left[ \frac{\hbar \omega}{2k_B T_2} + RT (\theta_1 + \theta_2) \Xi(\theta_1, \theta_2, \omega) \right]. \quad (B13) \]

where \(\Omega = e^{-\frac{\hbar \omega}{k_B T}}\) and \(k_B\) is the Boltzmann constant. Using the above equation, I represent \(\mathcal{P}_{33}^{off}\) as follows,
shown in Fig. 4. Note that $\Xi(\theta_\alpha, \theta_\beta, \omega)$ is zero at $\theta_\alpha = \theta_\beta$, and as a function of $\omega$ it changes a sign from positive to negative with increasing $\omega$. This sign change occurs around $h\omega = k_B(\theta_\alpha + \theta_\beta)$. At this temperature/frequency, the joint two terminal contribution to thermal noise vanishes.

Note that while expressing Eq. (B10) in terms of $F_{\alpha\beta}$, Eq. (15), I used,

$$\frac{1}{\hbar} \int dE \left\{ F_{\alpha\beta}(E, E + h\omega) - \frac{f_\alpha(E) + f_\beta(E + h\omega)}{2} \right\} = \left( \frac{\tau_0}{\hbar} \right) \int_{-\tau_0/2}^{\tau_0/2} dt \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} \left( G_{0,\alpha}^{(1)}(\tau) G_{0,\beta}^{(1)*}(\tau) \right).$$

(B14)

For examples, see Eq. (B9) and alike.

The excess auto-correlation noise reads,

$$\mathcal{P}_{33}^{ex}(\omega) = e^2 v_\mu^2 \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} \left\{ \left| R G_{0,1}^{(1)}(t + \tau; t) + T G_{0,2}^{(1)}(\tau) \right|^2 - \left| R G_{1}^{(1)}(t + \tau; t) + T G_{0,2}^{(1)}(\tau) \right|^2 \right\}. \quad \text{(B15)}$$

When both incoming channels are at the same temperature, $\theta_1 = \theta_2 = \theta$, and have the same Fermi energies, $\mu_1 = \mu_2 = \mu$, that is, their equilibrium correlation functions are the same, $G_{0,1} = G_{0,2} = G_0$, the above equation is simplified, [see Eq. (22a)]

$$\mathcal{P}_{33}^{ex}(\omega) = e^2 v_\mu^2 \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} \left\{ \left| R G_{0,1}^{(1)}(t + \tau; t) + T G_{0,2}^{(1)}(\tau) \right|^2 - \left| R G_{1}^{(1)}(t + \tau; t) + T G_{0,2}^{(1)}(\tau) \right|^2 \right\}. \quad \text{(B16)}$$

2. Cross-correlation noise

The cross-correlation noise in terms of $G^{(1)}$ was given in Ref. 50,

$$\mathcal{P}_{34}(\omega) = -R T e^2 v_\mu^2 \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} \left[ \left| G_{0,1}^{(1)}(t + \tau; t) - G_{0,2}^{(1)}(\tau) \right|^2 \right]. \quad \text{(B18)}$$

The excess cross-correlation noise reads,

$$\mathcal{P}_{34}^{ex}(\omega) = R T e^2 v_\mu^2 \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} \left\{ \left| G_{0,1}^{(1)}(t + \tau; t) - G_{0,2}^{(1)}(\tau) \right|^2 - \left| G_{1}^{(1)}(t + \tau; t) - G_{0,2}^{(1)}(\tau) \right|^2 \right\}. \quad \text{(B19)}$$

If both incoming channels are under the same conditions, $G_{0,1} = G_{0,2} = G_0$, then, unlike the auto-correlation noise, the cross-correlation noise has no equilibrium contribution and it is expressed solely in terms of the excess correlation function $G^{(1)}$, [see Eq. (22a)]

$$\mathcal{P}_{34}(\omega) = \mathcal{P}_{34}^{ex}(\omega) = -R T e^2 v_\mu^2 \int_{-\tau_0/2}^{\tau_0/2} \frac{dt}{\tau_0} \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} \left[ \left| G_{1}^{(1)}(t + \tau; t) \right|^2 \right]. \quad \text{(B20)}$$
3. The excess noise conservation at zero frequency

Conservation of charge imposes strong restrictions on zero frequency noise.\textsuperscript{14} Namely, in the case under consideration, $P_{33}^{ee}(0)$ and $P_{34}^{ee}(0)$ are perfectly anti-correlated, such that

$$P_{33}^{ee}(0) + P_{34}^{ee}(0) = 0.$$  \hfill (B21)

To show this, let us use Eqs. (B15) and (B19) and obtain,

$$\int \frac{dt}{T_0} \int d\tau \left| G_1^{(1)}(t + \tau; t) \right|^2 = (B22)$$

Then I use Eqs. (20), (19) and calculate the right hand side in the above equation,

$$r.h.s. = \frac{1}{\hbar v_0^2} \int dE f_1^2(E),$$  \hfill (B23)

and the left hand side,

$$l.h.s. = \frac{1}{\hbar v_0^2} \int dE \sum_{n,m,q} f_1(E_q) f_1(E) S_F^* \left( E_n, E \right) S_F \left( E_{m', E}, E \right) S_F^* \left( E_{m', E}, E_q \right) S_F \left( E_n, E_q \right).$$  \hfill (B24)

Using the unitarity of the Floquet scattering amplitude of the source in the above equation, see Eqs. (13) and (B4), I sum over $n$ and $m$ and get the following,

$$l.h.s. = \frac{1}{\hbar v_0^2} \int dE f_1^2(E) = r.h.s.,$$  \hfill (B25)

that is, Eq. (B22) is proven.

4. Noise and the outgoing correlation matrix of a linear electronic circuit

To generalize equations that relate noise to electron correlation functions to the case with several sources and/or with several outgoing channels, it is instructive to combine correlation functions of all incoming channels into a square matrix $G_{in}^{(1)}$, and of all outgoing channels into a square matrix $G_{out}^{(1)}$, see Ref. 43 for details. Their dimensions are equal to the number of incoming and outgoing channels, respectively. Let us denote by $S$ the scattering matrix of a stationary electronic circuit connecting incoming and outgoing channels. If $S$ is independent of the energy, the incoming and outgoing correlation matrix are related as follows, $G_{out}^{(1)}(t_1; t_2) = S^* G_{in}^{(1)}(t_1; t_2) S^T$, where the upper index $*$ means complex conjugation, and $T$ means transposition. Since the incoming channels are not correlated, $G_{in}^{(1)}$ is diagonal.

In the case of a single QPC considered in this work, $G_{in,11}^{(1)} = G_{1,1}^{(1)}$, $G_{in,22}^{(1)} = G_{2,2}^{(1)}$, and two other elements are zero. The circuit’s scattering matrix is given in Eq. (17), $S = S_{QPC}$. Then, the outgoing correlation matrix reads,

$$G_{out}^{(1)} = \begin{pmatrix} RG_{1,1}^{(1)} + TG_{2,2}^{(1)} & i\sqrt{RF} \left( G_{1,1}^{(1)} - G_{2,2}^{(1)} \right) \\ i\sqrt{RF} \left( G_{2,1}^{(1)} - G_{1,2}^{(1)} \right) & T G_{1,1}^{(1)} + R G_{2,2}^{(1)} \end{pmatrix}.$$  \hfill (B26)

Comparing the elements of $G_{out}^{(1)}$ to Eqs. (B15) and (B19), we can relate the excess noise and the elements of the outgoing correlation matrix as follows,

$$P_{\alpha\alpha'}^{ee}(\omega) = e^2 \int \frac{dt}{T_0} \int_{-T_0/2}^{T_0/2} d\tau e^{i\omega \tau}$$

$$\left\{ v_\mu G_{out,\alpha\alpha'}^{(1)\,off}(t + \tau; t) \right\}^2 - \left| v_\mu G_{out,\alpha\alpha'}^{(1)\,on}(t + \tau; t) \right|^2$$

where the upper indices $off$ and $on$ indicate that electronic sources are off and on, respectively.

Notice that in the above equation, the indices $\alpha$ and $\alpha'$ number outgoing channels only, therefore, $\alpha, \alpha' = 1, 2$. While in Eqs. (B15) and (B19), the outgoing channels were numbered together with incoming channels, hence the incoming channels were 3 and 4, respectively. Equation (B27) is applicable for any number of electronic sources and any number of outgoing channels.

Appendix C: Noise caused by an electron injected from a quantum level raising at a constant rapidity at zero temperature

In this appendix I derive Eqs. (28) starting from Eqs. (22).

First, I use the wave function $\psi^{(c)}$ from Eq. (6), and calculate the excess correlation function,

$$G^{(1)}(t + \tau; t) = \frac{\mathrm{e}^{i\pi \tau}}{\pi \Gamma \nu_\mu} \int_0^\infty dx e^{-x} \mathrm{e}^{ix + \frac{i\pi \tau}{\nu_\mu} + e^{-ix^2 \xi}}$$

$$\int_0^\infty dy e^{-y} \mathrm{e}^{iy \nu_\mu} \mathrm{e}^{-iy^2 \xi}.$$  \hfill (C1)
Here I introduced the parameter of non-adiabaticity $\zeta = \tau_D / \Gamma_\tau$. This parameter controls the symmetry of the density profile of the injected wave packet.\cite{42} With a symmetric density profile, injection is classified as adiabatic, with an asymmetric density profile, injection is non-adiabatic.\cite{45} At $\zeta = 0$, this source is identical to the source of levitons, that is, $\psi^c = \psi^L$, see Eqs. (4) and (6).

At the next step, let us calculate separately two terms entering Eqs. (22). I assume $\Gamma_\tau \ll T_0$ and, therefore, extend the limits of integration over $t$ to infinity.

1. The term with $\mp^2 G_1^{(1)} g_0^{(1)*}$

I denote this term as $\Pi_1$. Using Eq. (20) for $g_0^{(1)}$ at zero temperature, I have,

$$\Pi_1(\omega) = -\int_{-\infty}^{\infty} d\tau e^{i\omega\tau} 2\text{Re} \frac{C(\tau)}{-2\pi i\tau},$$  \hspace{1cm} (C2)

$$C(\tau) = \frac{1}{\pi \tau} \int_{-\infty}^{\infty} dt \int_{0}^{\infty} dx e^{-x} e^{ix\frac{t}{\tau}} e^{-ix^2\tau} \zeta,$$

$$\times \int_{0}^{\infty} dy e^{-y^2} e^{-iy^2\tau} e^{iy^2\zeta}.$$ 

First, I evaluate coherence $C(\tau)$. For this, I integrate over $t$,

$$\int_{-\infty}^{\infty} dt e^{ix\frac{t}{\tau}} e^{-iy\frac{t}{\tau}} = 2\pi \Gamma_\tau \delta(x-y).$$

This allows us to integrate, say, over $y$ (the result is independent of the parameter of non-adiabaticity $\zeta$),

$$C(\tau) = 2 \int_{0}^{\infty} dx e^{-2x} e^{ix\frac{t}{\tau}} = \frac{1}{1 - i\tau / (2\Gamma_\tau)}.$$  \hspace{1cm} (C3)

Substituting the above equation into Eq. (C2), I calculate

$$\Pi_1(\omega) = e^{-|\omega|2\Gamma_\tau}.$$  \hspace{1cm} (C4)

2. The term with $\mp^2 |G^{(1)}|^2$

I denote this term as $\Pi_2$,

$$\Pi_2(\omega) = \int_{-\infty}^{\infty} dt \int_{-\infty}^{\infty} d\tau e^{i\omega\tau} \left| \psi^c(t + \tau) \right|^2 \left| \psi^c(t) \right|^2.$$  \hspace{1cm} (C5)

First, I shift $\tau + t \rightarrow \tau$, and represent the above equation as the square of the Fourier transform of the wave packet density, $\Pi_2(\omega) = |\mathcal{N}(\omega)|^2$, where

$$\mathcal{N}(\omega) = \Gamma_\tau \int_{-\infty}^{\infty} dze^{i\omega \Gamma_\tau z} \left| \psi^c(\Gamma_\tau z) \right|^2 = \frac{1}{\pi} \int_{-\infty}^{\infty} dze^{i\omega \Gamma_\tau z}$$

$$\times \int_{0}^{\infty} dx e^{-x} e^{ix\zeta} e^{-ix^2\zeta} \int_{0}^{\infty} dy e^{-y^2} e^{iy^2z} e^{iy^2\zeta},$$

where $z = \tau / \Gamma_\tau$. The integration over $z$ gives,

$$\int_{-\infty}^{\infty} dze^{i\omega \Gamma_\tau z} e^{ixz} e^{-iyz} = 2\pi \delta(\omega \Gamma_\tau + x - y).$$

Then I integrate over $y = x + \omega \Gamma_\tau$ (for positive $\omega$),

$$\mathcal{N}(\omega) = 2e^{i(\omega \Gamma_\tau)^2} e^{-\omega \Gamma_\tau} \int_{0}^{\infty} dx e^{-2xe^{i2\omega \Gamma_\tau} z}$$

$$= e^{i(\omega \Gamma_\tau)^2} e^{-\omega \Gamma_\tau} (1 - i\omega \Gamma_\tau \zeta),$$

and obtain (for arbitrary $\omega$),

$$\Pi_2(\omega) = e^{-|\omega|2\Gamma_\tau} \frac{1}{1 + (\omega \tau_D \zeta)},$$  \hspace{1cm} (C7)

where $\tau_D = \Gamma_\tau \zeta$. This term fully defines cross-correlation noise and partially auto-correlation noise.

3. Excess noise power

By combining both terms together, I get,

$$\mathcal{P}_{33}^{ex}(\omega) = R^2 e^{2R \Pi_1(\omega)} - R^2 e^{2R \Pi_2(\omega)}$$  \hspace{1cm} (C8)

$$\mathcal{P}_{34}^{ex}(\omega) = -RT e^{2R \Pi_2(\omega)}.$$
Using Eqs. (C4) and (C7) we arrive at Eq. (28).

Note that at $\omega = 0$, $\Pi_1(0) = \Pi_2(0)$ and $P_{\Sigma_1}^{\omega}(0) = P_{\Sigma_3}^{\omega}(0) = 0$ in agreement with Eq. (B21).

**Appendix D: Noise caused by an electron injected from a quantum level raising at a constant rapidity at non-zero temperature**

In this appendix, I repeat the calculations presented in the previous Appendix, but at non-zero temperatures, and compute the temperature-dependent factor $\eta(\omega, \theta)$ from Eq. (29).

For this model, the correlation function of electrons injected at a nonzero temperature, $\theta > 0$, was expressed in terms of the correlation function at zero temperature in Ref. 59,

$$G_{1,0}^{(1)}(t + \tau; t) = \int dc \left( -\frac{\partial f_1}{\partial c} \right) e^{i\frac{\tau}{\theta}}G_{1,0}^{(1)}(t + \tau - \frac{e}{c}; t - \frac{e}{c}) \tag{D1}$$

Here the indices $\theta$ and 0 refer to non-zero and zero temperatures, respectively, $f_1$ is the Fermi distribution function for electrons with temperature $\theta$ in lead 1, which the additional electron is injected into, $G_{1,0}^{(1)}$ is given in Eq. (C1), and the rapidity $c = \hbar/(2\tau_D \Gamma)$, see Eq. (6).

The above equation can be interpreted as the correlation function for a single-particle mixed quantum state with component states distributed according to the thermal probability density $\rho(\epsilon) = -\partial f_1(\epsilon)/\partial \epsilon$ and having correlation functions $\epsilon^{i\frac{\tau}{\theta}}G_{1,0}^{(1)}(t + \tau - \frac{e}{c}; t - \frac{e}{c})$.

1. **The term with $-v_\mu^2 |G^{(1)}_{\theta 0}|^2$**

Using Eqs. (D1) and (20), I calculate

$$\Pi_1(\omega) = \int_{-\infty}^{\infty} d\tau e^{i\omega \tau} \left( \frac{1}{\sinh (\tau/\theta)} \right) \frac{1}{\tau \theta} \int_{-\infty}^{\infty} dc e^{i\frac{\tau}{\theta}} \frac{\partial f_1}{\partial \epsilon} \left[ \epsilon^{i\frac{\tau}{\theta}}G_{1,0}^{(1)}(t + \tau - \frac{e}{c}; t - \frac{e}{c}) \right] \tag{D2}$$

Here

$$\Pi_1(\omega) = \int_{-\infty}^{\infty} d\tau e^{i\omega \tau} \left( \frac{\tau/\theta}{\sinh (\tau/\theta)} \right) \frac{1}{\tau \theta} \int_{-\infty}^{\infty} dc e^{i\frac{\tau}{\theta}} \frac{\partial f_1}{\partial \epsilon} \left[ \epsilon^{i\frac{\tau}{\theta}}G_{1,0}^{(1)}(t + \tau - \frac{e}{c}; t - \frac{e}{c}) \right] \tag{D3}$$

With $G^{(1)}_{\theta 0}$ from Eq. (C1), I calculate $\mathcal{C}(\tau)$ as described above in Appendix C1 and find,

$$\Pi_1(\omega) = \int_{-\infty}^{\infty} d\tau e^{i\omega \tau} \left( \frac{\tau/\theta}{\sinh (\tau/\theta)} \right) \frac{1}{\tau \theta} \int_{-\infty}^{\infty} dc e^{i\frac{\tau}{\theta}} \frac{\partial f_1}{\partial \epsilon} \left[ \epsilon^{i\frac{\tau}{\theta}}G_{1,0}^{(1)}(t + \tau - \frac{e}{c}; t - \frac{e}{c}) \right] \tag{D4}$$

Remind that the thermal coherence time $\tau_\theta = \hbar/(\pi k_B \theta)$.

At $\theta_1 = 0$ we recover Eq. (C4). Note that $\Pi_1(\omega)$ obeys Eq. (27).

2. **The term with $v_\mu^2 |G^{(1)}_{\theta 0}|^2$**

At non-zero temperature the corresponding term reads,

$$\Pi_2(\omega) = \int_{-\infty}^{\infty} d\epsilon e^{i\omega \epsilon} \rho(\epsilon) p(\epsilon') |\mathcal{N}_{\epsilon - \epsilon'}(\omega)|^2 . \tag{D5}$$

Here the thermal probability density $p(\epsilon) = -\partial f_1(\epsilon)/\partial \epsilon$, and

$$\mathcal{N}_{\epsilon - \epsilon'}(\omega) = \frac{1}{\pi} \int_{-\infty}^{\infty} dz e^{i\omega(z - \epsilon')} 2\Gamma \sinh (z/\pi) \int_{-\infty}^{\infty} dz' e^{i\omega(z' - \epsilon')} 2\Gamma \sinh (z'/\pi) \int_{-\infty}^{\infty} dy e^{-i\omega y} e^{i\epsilon y} e^{i\epsilon' y} \tag{D6}$$

where $z = \tau/\Gamma$. Up to an irrelevant phase factor, $\mathcal{N}_{\epsilon - \epsilon'}(\omega)$ is the same as $\mathcal{N}(\omega)$ from Eq. (C6). Therefore, we can write,

$$\Pi_2(\omega) = \frac{1}{1 + (\omega \tau_D)^2} \int_{-\infty}^{\infty} d\epsilon e^{i\omega \epsilon} \rho(\epsilon) p(\epsilon') e^{-i\omega \epsilon} e^{-i\epsilon' \epsilon} e^{2\Gamma \sinh (\epsilon/\pi)} \tag{D7}$$

To bring the above equation into the form close to $\Pi_1$, Eq. (D4), let us represent the exponential factor as follows,

$$e^{-i\omega \epsilon} e^{-i\epsilon' \epsilon} e^{2\Gamma \sinh (\epsilon/\pi)} = \frac{1}{2\pi \Gamma} \int_{-\infty}^{\infty} d\tau e^{i(\omega + \epsilon') \tau} 2\Gamma \Theta(\tau) \int_{-\infty}^{\infty} d\tau e^{-i(\omega + \epsilon') \tau} 2\Gamma \Theta(\tau) \tag{D8}$$
Then we can integrate over \( \epsilon \) and \( \epsilon' \) in Eq. (D7) as follows,

\[
\int d\epsilon p(\epsilon) e^{\epsilon^2/\tau} \tau/\theta = \frac{\tau/\theta}{\sinh (\tau/\theta)},
\]

and find that

\[
\Pi_2(\omega) = \frac{1}{1 + (\omega \tau_d)^2} \int_{-\infty}^{\infty} d\tau e^{i\omega \tau} \left( \frac{\tau/\theta}{\sinh (\tau/\theta)} \right)^2 \frac{(\omega/\tau)^2}{1 + \tau^2 / (2 \Gamma)^2} \tag{D8}
\]

where \( \Pi_1 \) is given in Eq. (D4).

Notice that we cannot use the inverse Fourier transformation with respect to \( \omega \) in order to express \( \Pi_2(\omega) \) at temperature \( \theta \) in terms of \( \Pi_2(\omega) \) at zero temperature. As a result, the excess noise, Eq. (C8), does not obey Eq. (27).

3. Excess noise power

The relation between \( \Pi_2(\omega) \) and \( \Pi_1(\omega) \), Eq. (D8), is independent on temperature. Therefore, in the case under consideration, temperature affects equally both auto- and cross-correlation noise at any frequency,

\[
P_{\text{xx}}^e(\omega) = R e^{2} T + \frac{(\omega \tau_d)^2}{\tau_0^2 + (\omega \tau_d)^2} e^{-|\omega|2\Gamma \tau} \eta(\omega, \theta), \tag{D9}
\]

where

\[
\eta(\omega, \theta) = e^{-|\omega|2\Gamma \tau} \int_{-\infty}^{\infty} d\epsilon e^{i\omega \epsilon} \left( \frac{\tau/\theta}{\sinh (\tau/\theta)} \right)^2 \frac{1 + \epsilon^2 / (2 \Gamma)^2}{1 + \tau^2 / (2 \Gamma)^2}. \tag{D10}
\]

This factor is shown in Eq. (29), where I introduced \( x = \tau / (2 \Gamma \tau) \).

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